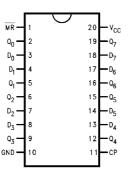


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Ordening Code.	

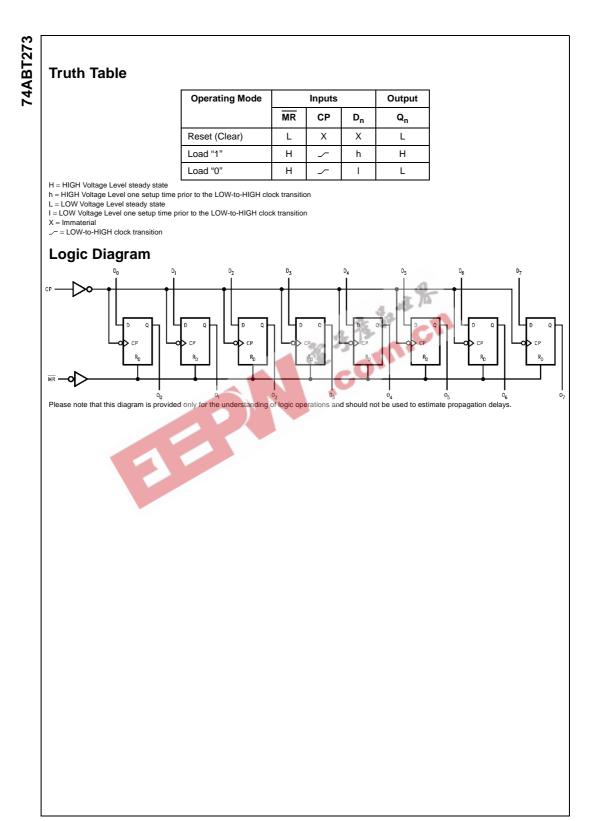
Order Number	Package Number		Package Description				
74ABT273CSC	M20B	20-Lead Sma	Il Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body				
74ABT273CSJ	M20D	20-Lead Sma	II Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide				
74ABT273CMSA	MSA20	20-Lead Shrir	nk Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide				
74ABT273CMTC	MTC20	20-Lead Thin	Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide				
Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.							

Connection Diagram



Pin Descriptions

Pin Names	Description
D ₀ -D ₇	Data Inputs
MR	Master Reset (Active LOW)
CP	Clock Pulse Input (Active Rising Edge)
Q ₀ –Q ₇	Data Outputs



Absolute Maximum Ratings(Note 1) **Recommended Operating** Conditions -65°C to +150°C Storage Temperature Ambient Temperature under Bias -55°C to +125°C Free Air Ambient Temperature -40°C to +85°C Junction Temperature under Bias $-55^{\circ}C$ to $+150^{\circ}C$ Supply Voltage +4.5V to +5.5V V_{CC} Pin Potential to Ground Pin -0.5V to +7.0V Minimum Input Edge Rate $(\Delta V/\Delta t)$ Input Voltage (Note 2) -0.5V to +7.0V 50 mV/ns Data Input Input Current (Note 2) -30 mA to +5.0 mA 20 mV/ns Enable Input Voltage Applied to Any Output in the Disabled or Power-Off State -0.5V to +4.75V –0.5V to $V_{\mbox{\scriptsize CC}}$ in the HIGH State Current Applied to Output twice the rated I_{OL} (mA) Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation in LOW State (Max) DC Latchup Source Current –500 mA under these conditions is not implied. (Across Comm Operating Range) Note 2: Either voltage limit or current limit is sufficient to protect inputs. Over Voltage Latchup $V_{CC} + 4.5V$

DC Electrical Characteristics

	age Latchup ectrical Characteristic	V _{CC} +.	4.5V			13	
Symbol	Parameter	Min	Тур	Max 🧹	Units	V _{cc}	Conditions
V _{IH}	Input HIGH Voltage	2.0		38. 1	V	1	Recognized HIGH Signal
V _{IL}	Input LOW Voltage			0.8	V		Recognized LOW Signal
V _{CD}	Input Clamp Diode Voltage			-1.2	V	Min	I _{IN} = -18 mA
V _{OH}	Output HIGH Voltage	2.5 2.0	\sim		v	Min	I _{OH} = -3 mA I _{OH} = -32 mA
V _{OL}	Output LOW Voltage			0.55	V	Min	I _{OL} = 64 mA
IIH	Input HIGH Current			1 1	μΑ	Max	$V_{IN} = 2.7V$ (Note 3) $V_{IN} = V_{CC}$
I _{BVI}	Input HIGH Current Breakdown Test			7	μΑ	Max	V _{IN} = 7.0V
IIL	Input LOW Current			-1 -1	μA	Max	V _{IN} = 0.5V (Note 3) V _{IN} = 0.0V
V _{ID}	Input Leakage Test	4.75			V	0.0	I _{ID} = 1.9 μA All Other Pins Grounded
los	Output Short-Circuit Current	-100		-275	mA	Max	V _{OUT} = 0.0V
ICEX	Output HIGH Leakage Current			50	μΑ	Max	V _{OUT} = V _{CC}
ICCH	Power Supply Current			50	μΑ	Max	All Outputs HIGH
I _{CCL}	Power Supply Current			30	mA	Max	All Outputs LOW
I _{CCT}	Maximum I _{CC} /Input Outputs Enabled			1.5	mA	Max	$V_I = V_{CC} - 2.1V$ Data Input $V_I = V_{CC} - 2.1V$ All Others at V_{CC} or GND
ICCD	Dynamic I _{CC} No Load			0.3	mA/ MHz	Max	Outputs Open (Note 4) One Bit Toggling, 50% Duty Cycle

Note 3: Guaranteed but not tested.

Note 4: For 8 bits toggling, $I_{CCD} < 0.5 \mbox{ mA/MHz}.$

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AC Electrical Characteristics

Symbol	Parameter	$T_{A} = +25^{\circ}C$ $V_{CC} = +5.0V$ $C_{L} = 50 \text{ pF}$		$T_{A} = -55^{\circ}C \text{ to } +125^{\circ}C$ $V_{CC} = 4.5V \text{ to } 5.5V$ $C_{L} = 50 \text{ pF}$		$T_{A} = -40^{\circ}C \text{ to } +85^{\circ}C$ $V_{CC} = 4.5V \text{ to } 5.5V$ $C_{L} = 50 \text{ pF}$		Units	
		Min	Тур	Max	Min	Max	Min	Max	
f _{MAX}	Maximum Clock Frequency	150	200		150		150		MHz
t _{PLH}	Propagation Delay	2.0		6.0	1.0	7.0	2.0	6.0	ns
t _{PHL}	CP to O _n			6.8	1.0	7.5	2.8	6.8	115
t _{PHL}	Propagation Delay MR to O _n	2.5		7.4	1.0	8.2	2.5	7.4	ns

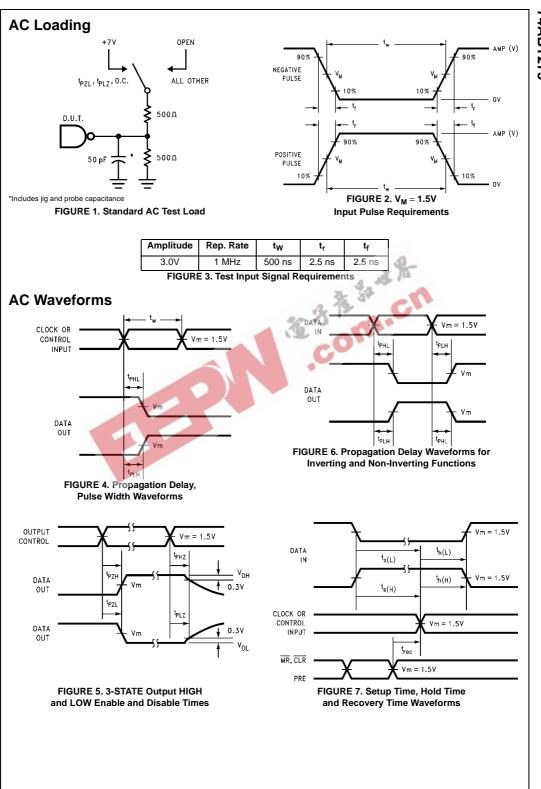
AC Operating Requirements

Symbol	Parameter	$T_{A} = +25^{\circ}C$ $V_{CC} = +5.0V$ $C_{L} = 50 \text{ pF}$		$T_A = -55^{\circ}C \text{ to } +125^{\circ}C$ $V_{CC} = 4.5V \text{ to } 5.5V$ $C_L = 50 \text{ pF}$		$T_{A} = -40^{\circ}C \text{ to } +85^{\circ}C$ $V_{CC} = 4.5V \text{ to } 5.5V$ $C_{L} = 50 \text{ pF}$		Units
		Min	Max	Min	Max	Min	Max	
t _S (H)	Setup Time, HIGH	2.0		2.0		2.0		ns
t _S (L)	or LOW D _n to CP	2.5		2.5	4 . ³⁰ '	2.5		115
t _H (H)	Hold Time, HIGH	1.2		1.4	3	1.2		
t _H (L)	or LOW D _n to CP	1.2		1.4		1.2		ns
t _W (H)	Pulse Width, CP,	3.3	X	3.3	2	3.3		ns
t _W (L)	HIGH or LOW	3.3	131	3.3		3.3		115
t _W (L)	Master Reset Pulse	3.3		3.3		3.3		
	Width, LOW	3.3		3.3		3.3		ns
t _{REC}	Recovery Time	2.0		2.0		2.0		20
	MR to CP	2.0		2.0		2.0		ns

Capacitance

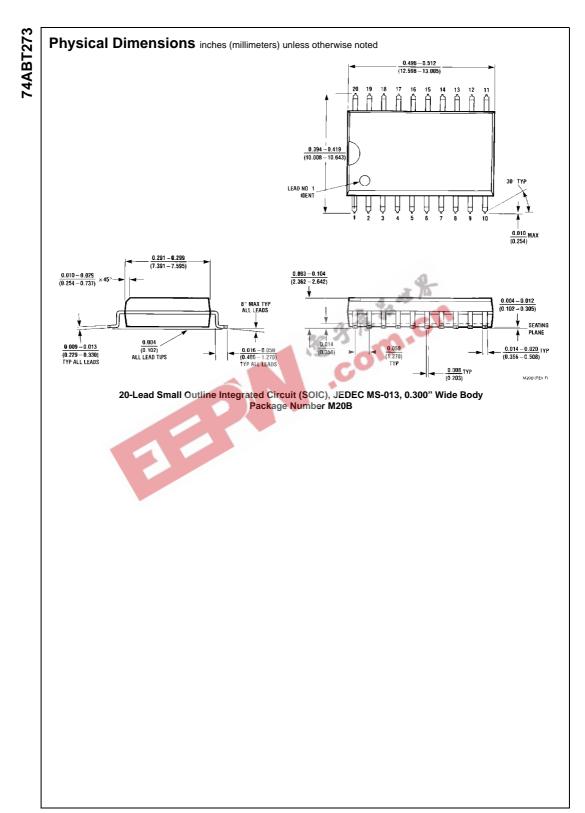
(SOIC package)				_
Symbol	Parameter	Тур	Units	Conditions T _A = 25°C
C _{IN}	Input Capacitance	5	pF	$V_{CC} = 0V$
C _{OUT} (Note 5)	Output Capacitance	9	pF	$V_{CC} = 5.0V$

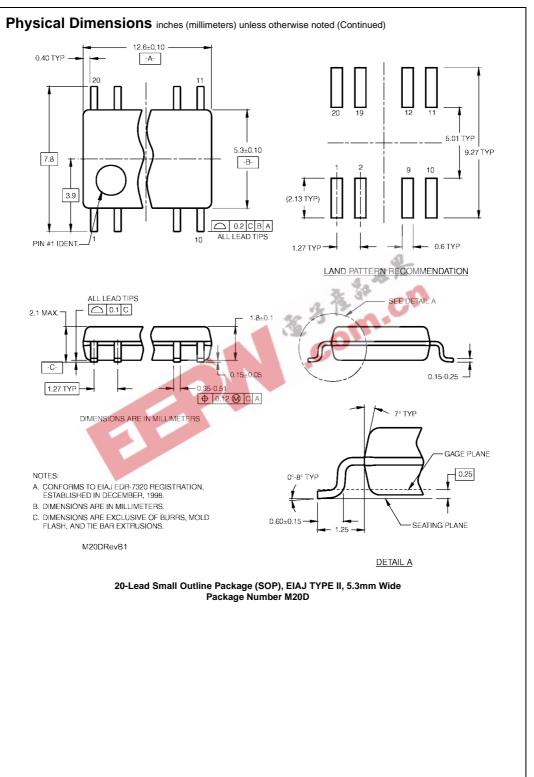
Note 5: C_{OUT} is measured at frequency f = 1 MHz, per MIL-STD-833, Method 3012.



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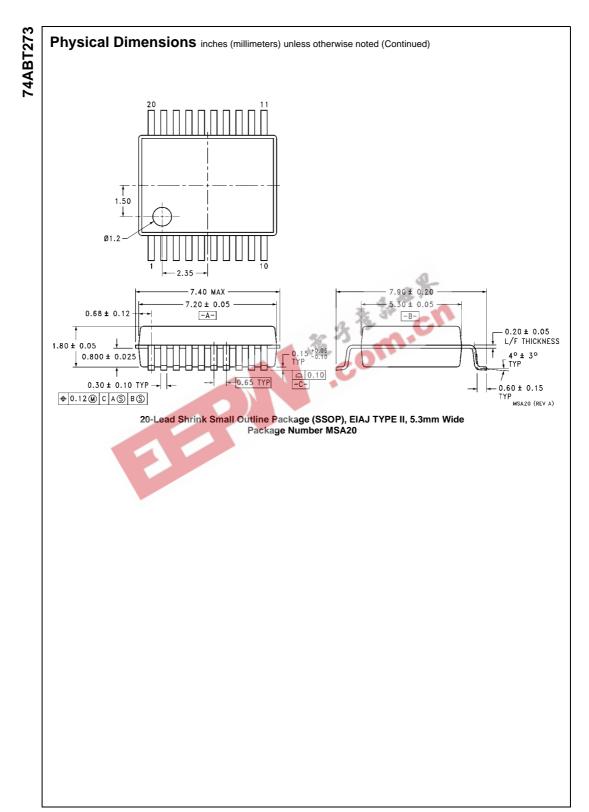
www.fairchildsemi.com

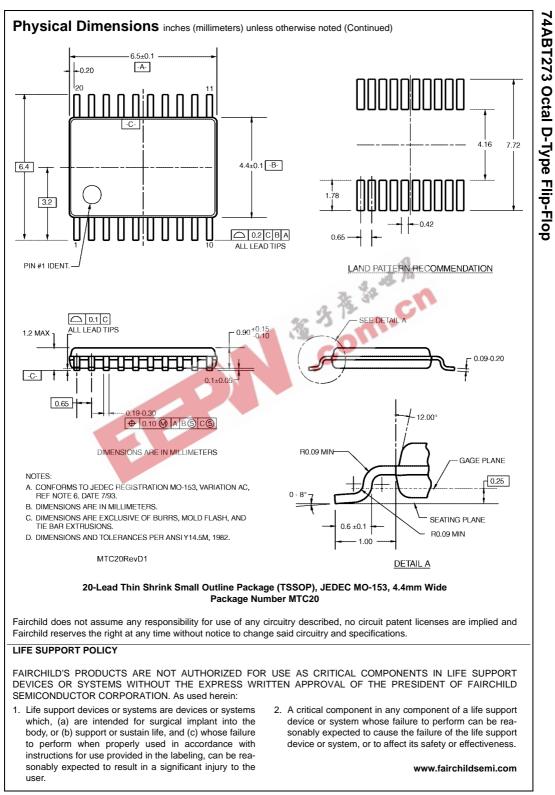




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